



Nb_3Sn R&D at Fermilab

Sam Posen

Linear Collider Workshop 2018

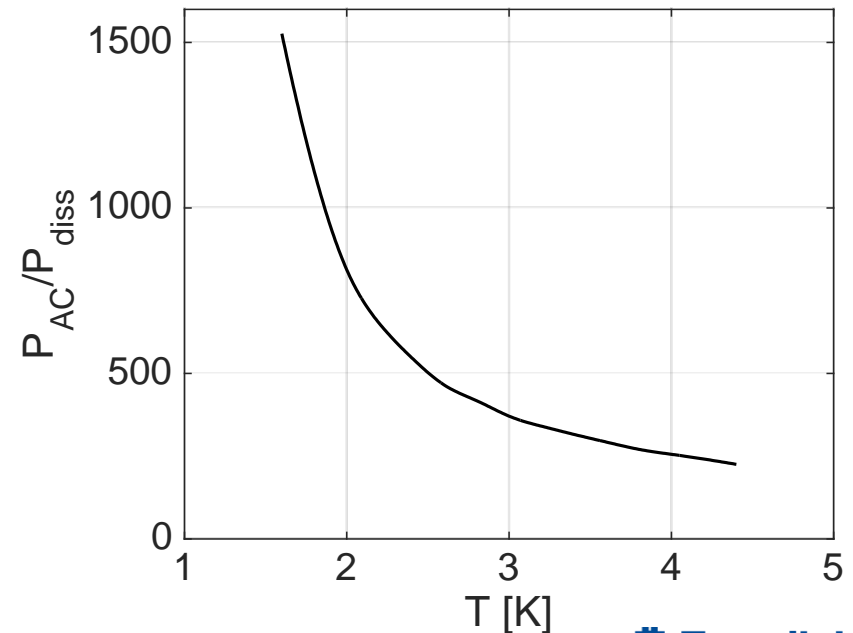
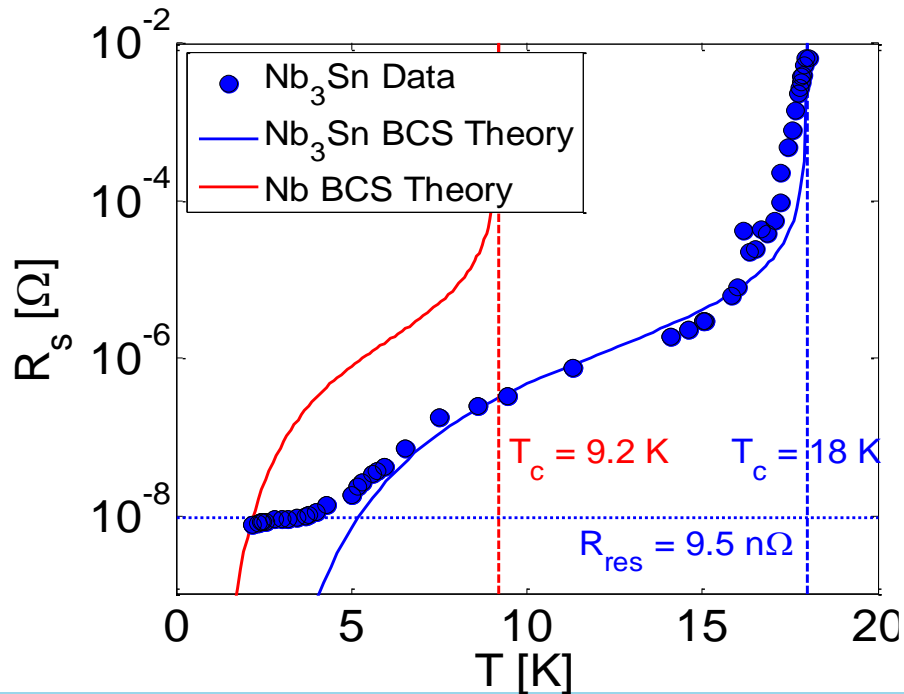
October 25, 2018

Higher $Q_0(T)$ with Nb_3Sn

- Large $T_c \sim 18$ K
 - Very small $R_{BCS}(T) - R_{BCS}(T) \sim e^{-1.76T_c/T}$
 - High Q_0 even at relatively high T
- Higher temperature operation
 - Simpler cryogenic plant
 - Higher efficiency

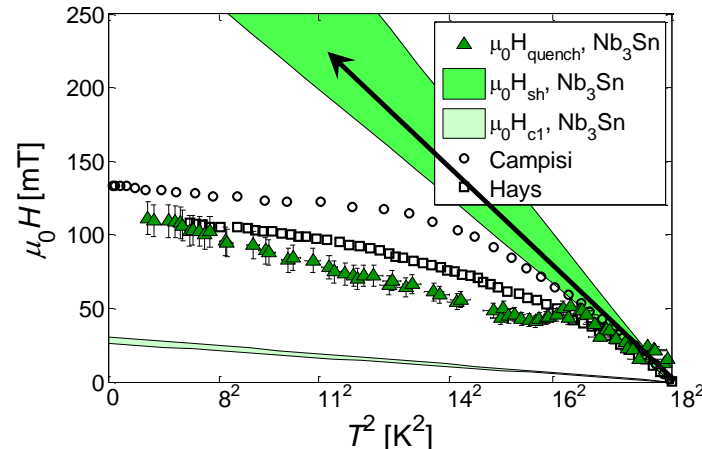
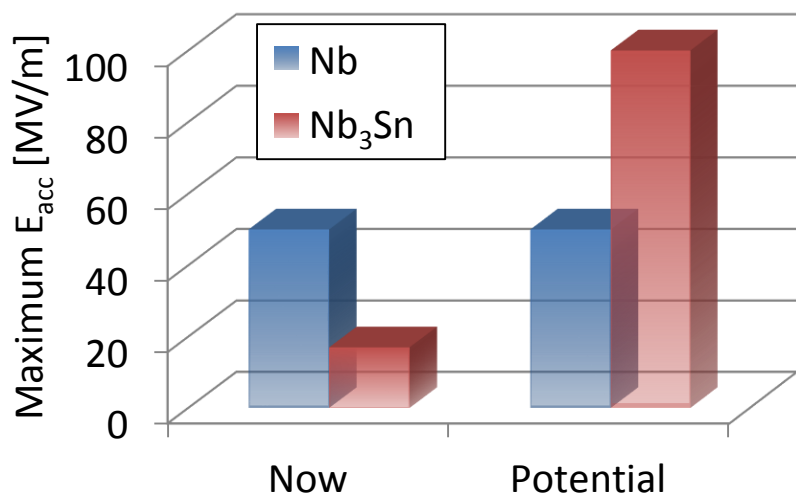


CERN cryogenic plant



Maximum Accelerating Field

- For high gradient applications, the superheating field of Nb_3Sn is predicted to be twice that of niobium
- This is significantly beyond current performance levels
- **Potential for high gradient applications (e.g. future >250 GeV ILC upgrade) motivates R&D focused on improving maximum field**



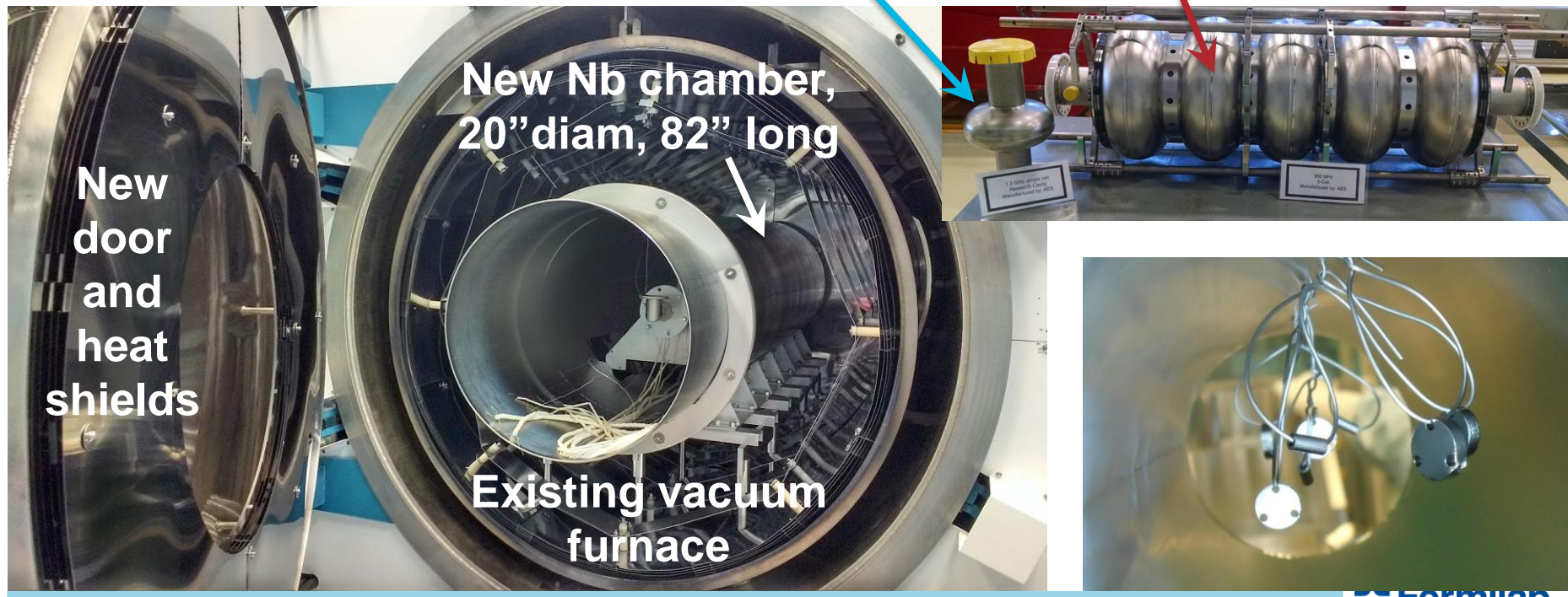
S. Posen, N. Valles, and M. Liepe, *Phys. Rev. Lett.*, 115, 047001 (2015).

Nb₃Sn SRF Experimental Program at Fermilab

- Initiated in 2015, first coatings by early 2017
- Nb₃Sn SRF program goals:
 1. Push Nb₃Sn cavity performance (both Q_0 and E_{acc})
 2. Scale up to production-style cavities and study in cryomodule-like environment

1.3 GHz 1-cell (current state of Nb₃Sn R&D)

650 MHz 5-cell (future)



Coating Parameter Optimization

- To date, best appearance and performance at Fermilab achieved with:
 - Smallest diameter crucible tested
 - Heater at maximum power (crucible ~ 1200 C)
 - Cavity anodized to 30 V prior to coating

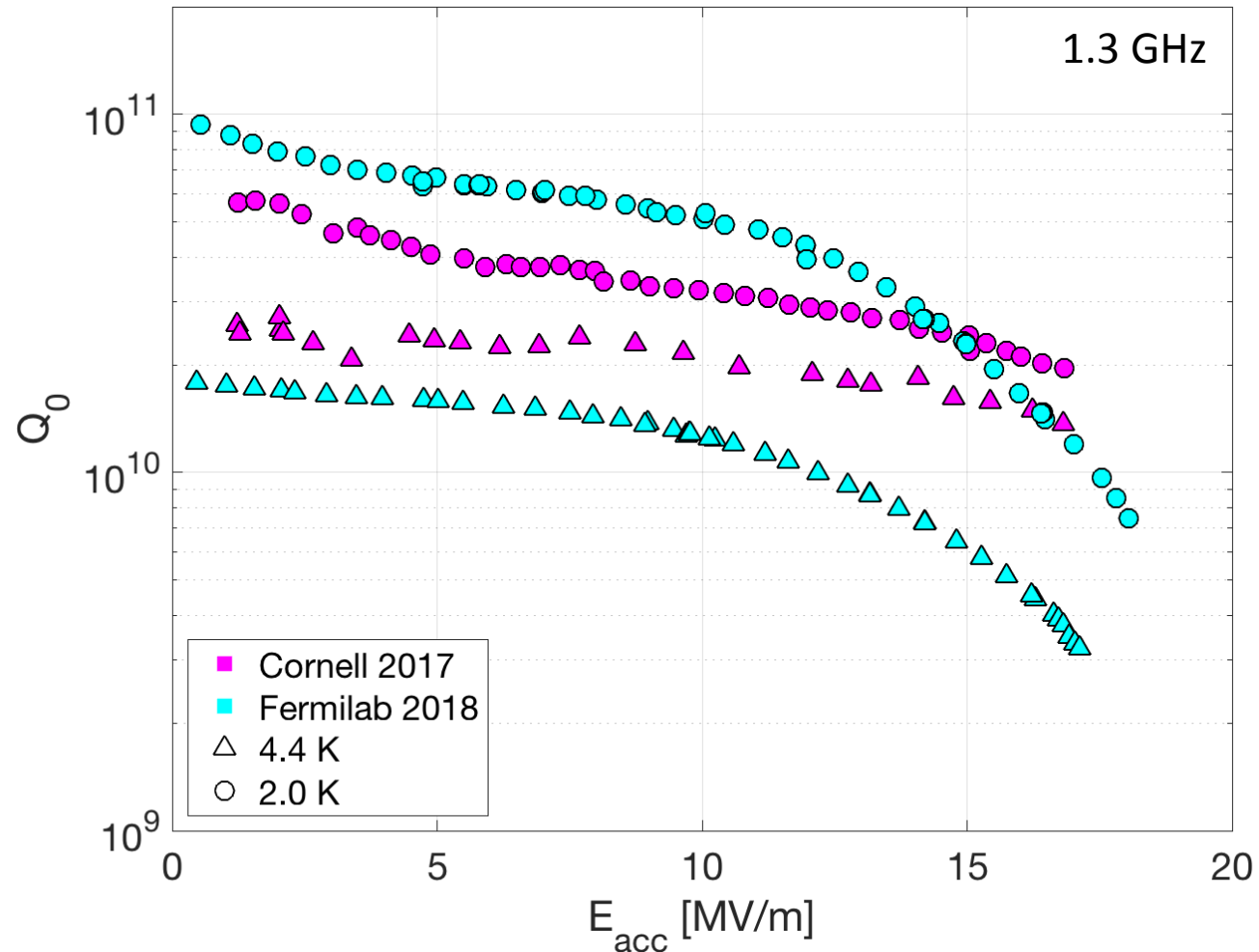


S. Posen, TTC Meeting 2018, Tokyo, Japan

Q vs E

S. Posen, TTC Meeting 2018, Tokyo, Japan

- Very high Q_0 at 2.0 K $\sim 5e10$ at useful fields ~ 10 MV/m
- Excellent low and mid-field Q_0 at 4.4 K $>1e10$
- Still some Q-slope but nice quench field
- Sharp 18 K transitions

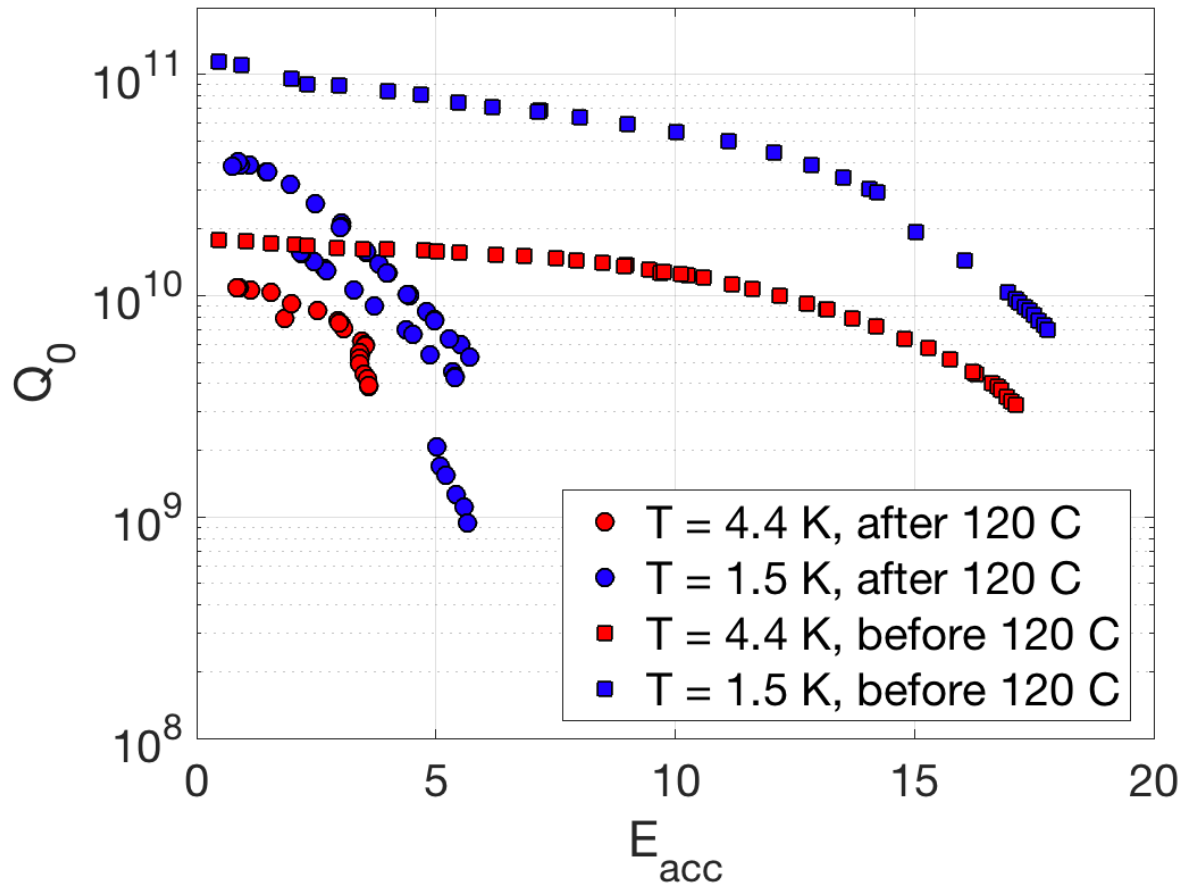


Nb at 2.0 K, 10 MV/m: $\sim 1 \times 10^{10} - 3 \times 10^{10}$

Nb at 4.4 K, 10 MV/m: $\sim 3 \times 10^8 - 5 \times 10^8$

120 C Bake Experiment

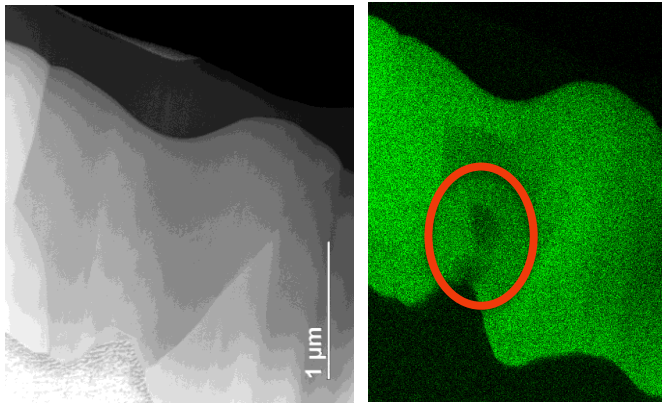
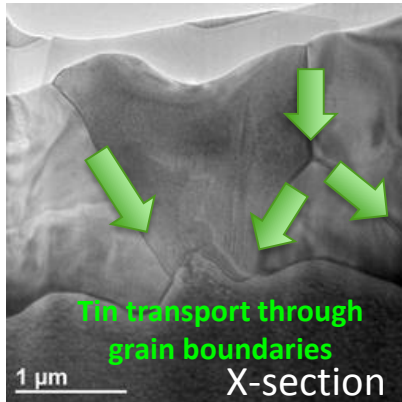
- 120 C 48 h bake increases maximum gradient of Nb cavities
- Simple study: what is effect of 120 C on Nb₃Sn?



Increasing E_{acc} in Nb_3Sn Cavities

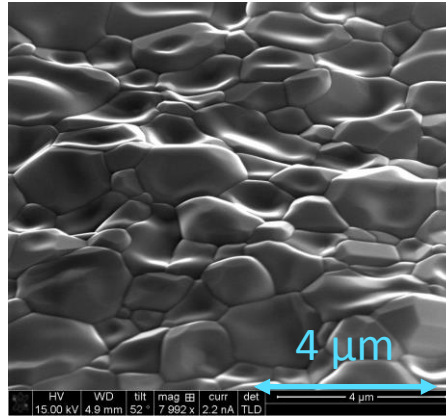
- Several promising paths forward for continued progress including:

Reducing low tin content regions

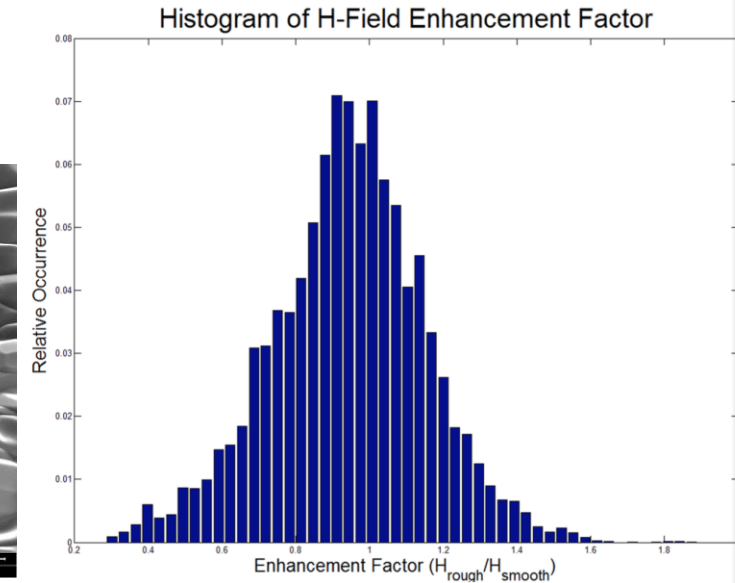
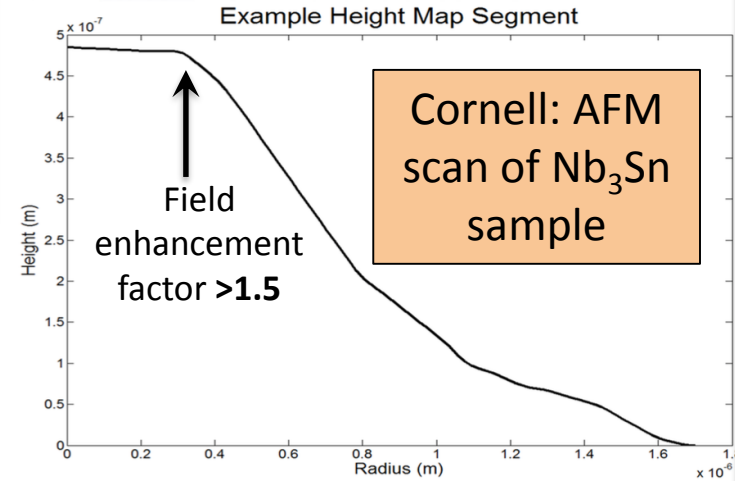


Y. Trenikhina, S. Posen, D. Hall, and M. Liepe, Proc. SRF Conference 2015, TUPB056, 2015

Smoothing sharp-edged surfaces



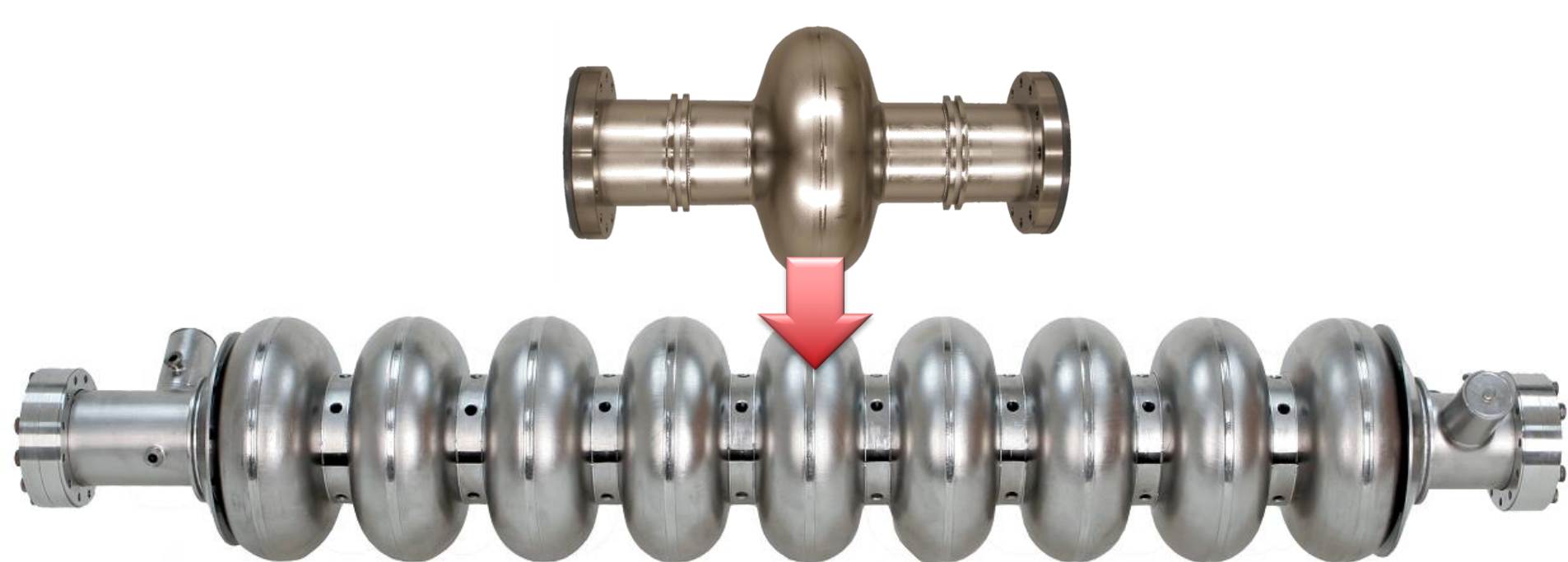
S. Posen, Ph.D. Thesis, Cornell University (2015).



R. Porter, D. L. Hall, M. Liepe, J. T. Maniscalco, Proc. Linac Conference 2016, MOPRC027 (2016).

Scaling Up to Large Cavities

- Coating a 9-cell TeSLA cavity is quite different from the single cell 1.3 GHz cavities with strong Nb₃Sn performance recently
- Intermediate steps possible?

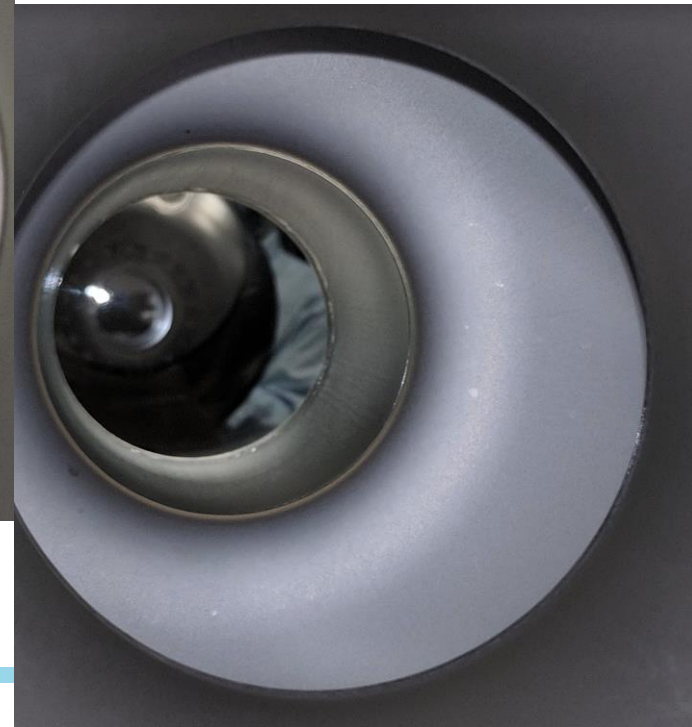
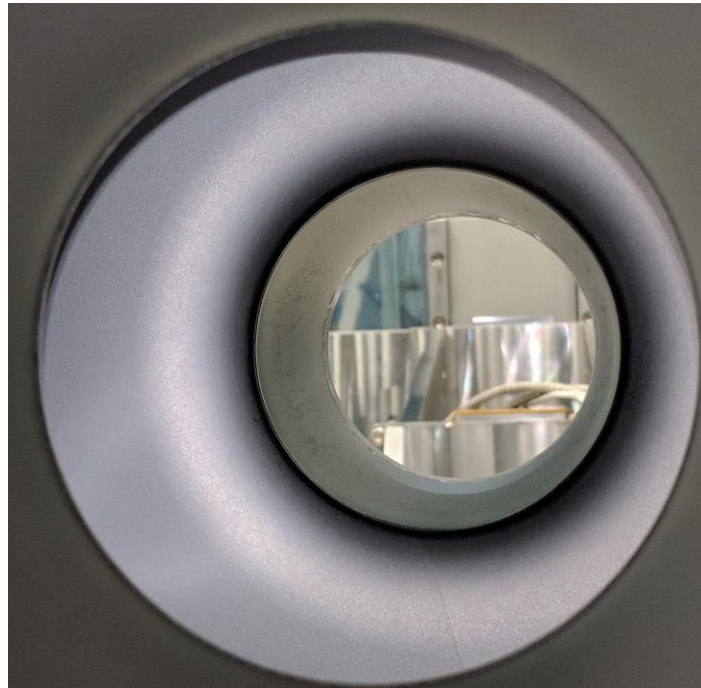
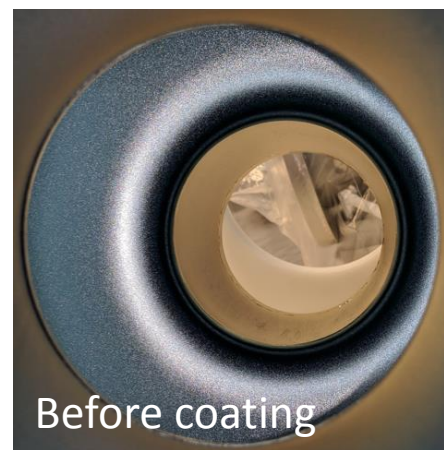




Nb₃Sn coating of single cell 650 MHz Cavity

650 MHz Cavity Coating

- First coating attempt using these parameters: 2.6 g of tin, 0.8 g SnCl_2 , cavity anodized to 30 V, 7 hours with furnace at 1100 C, including 4 hours at maximum heater temperature

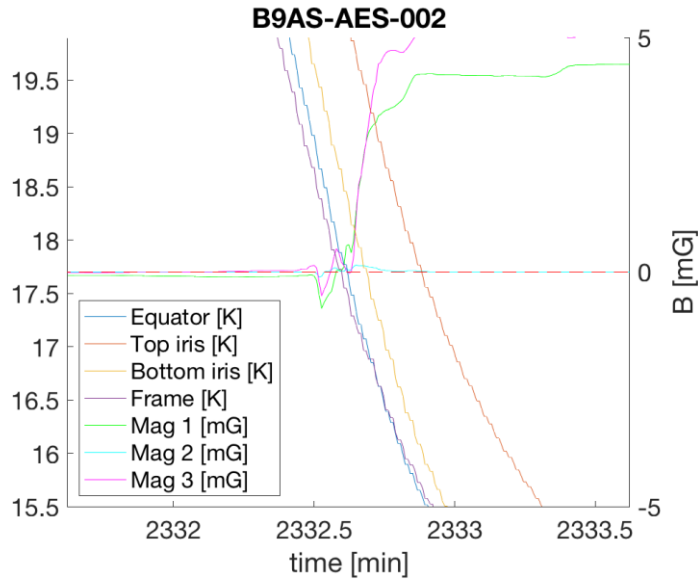


Testing Schedule

- Day 1:
 - Cooldown 0: non-uniform – transfer liquid out and cool again
 - Cooldown 1: uniform – Q vs E at 4.4 K (multipacting limited)
- Day 2:
 - Cooldown 2 – Q vs E in helium gas between 4.5 K – 6.5 K
- Day 3:
 - Still cold – Q vs T down to 2 K, Q vs E at 2 K
- Day 4:
 - Cooldown 3: magnetic field applied – Q vs E at 4.4 K

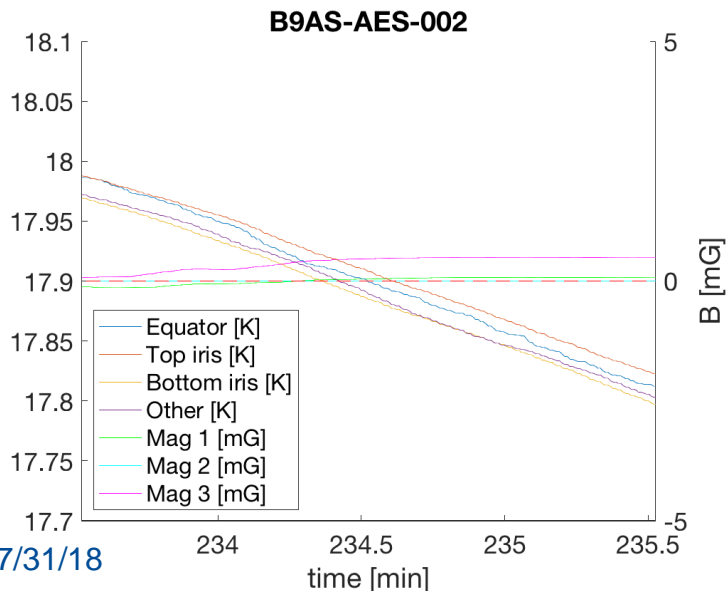


Day 1



Cooldown 0:

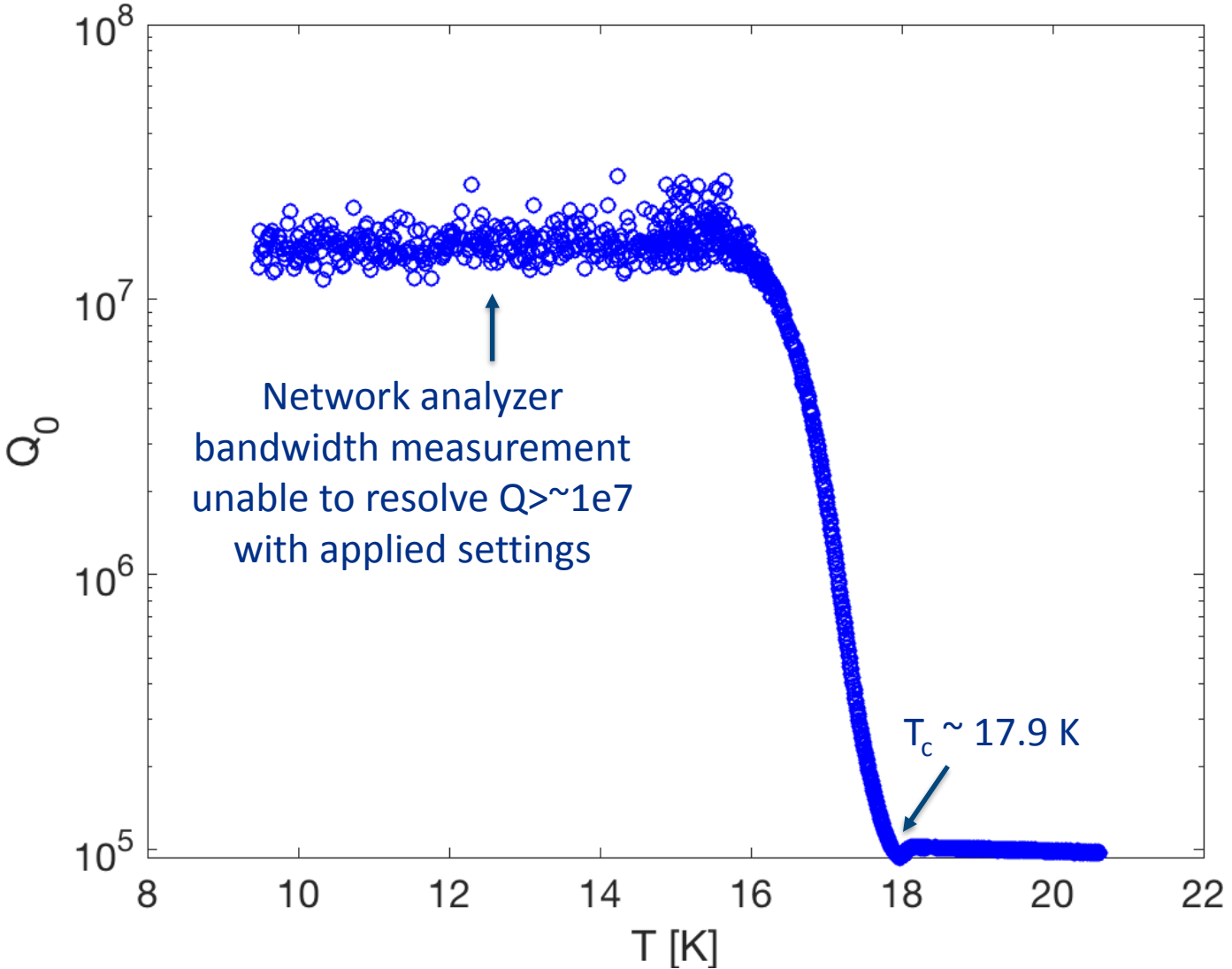
- Non-uniform cooldown
- $\Delta T \sim 3$ K
- Compensated ambient field
- High residual resistance – transferred liquid out, warmed above T_c and cooled down again



Cooldown 1

- Carefully controlled cooldown
- $\Delta T \sim 20$ mK
- Compensated ambient field

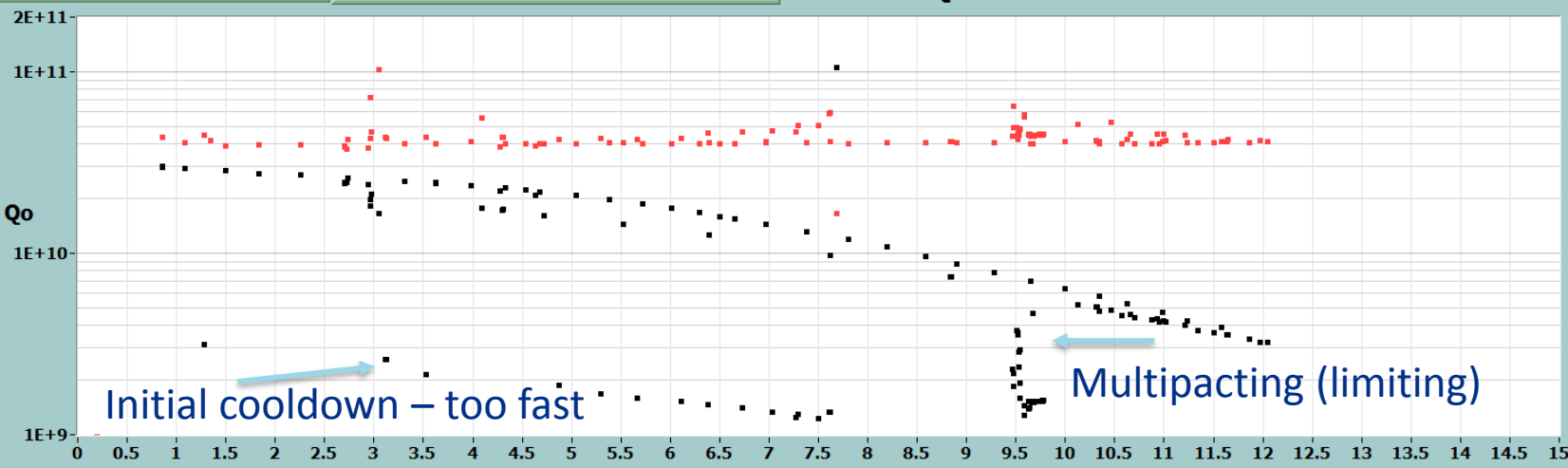
Q vs T from network analyzer



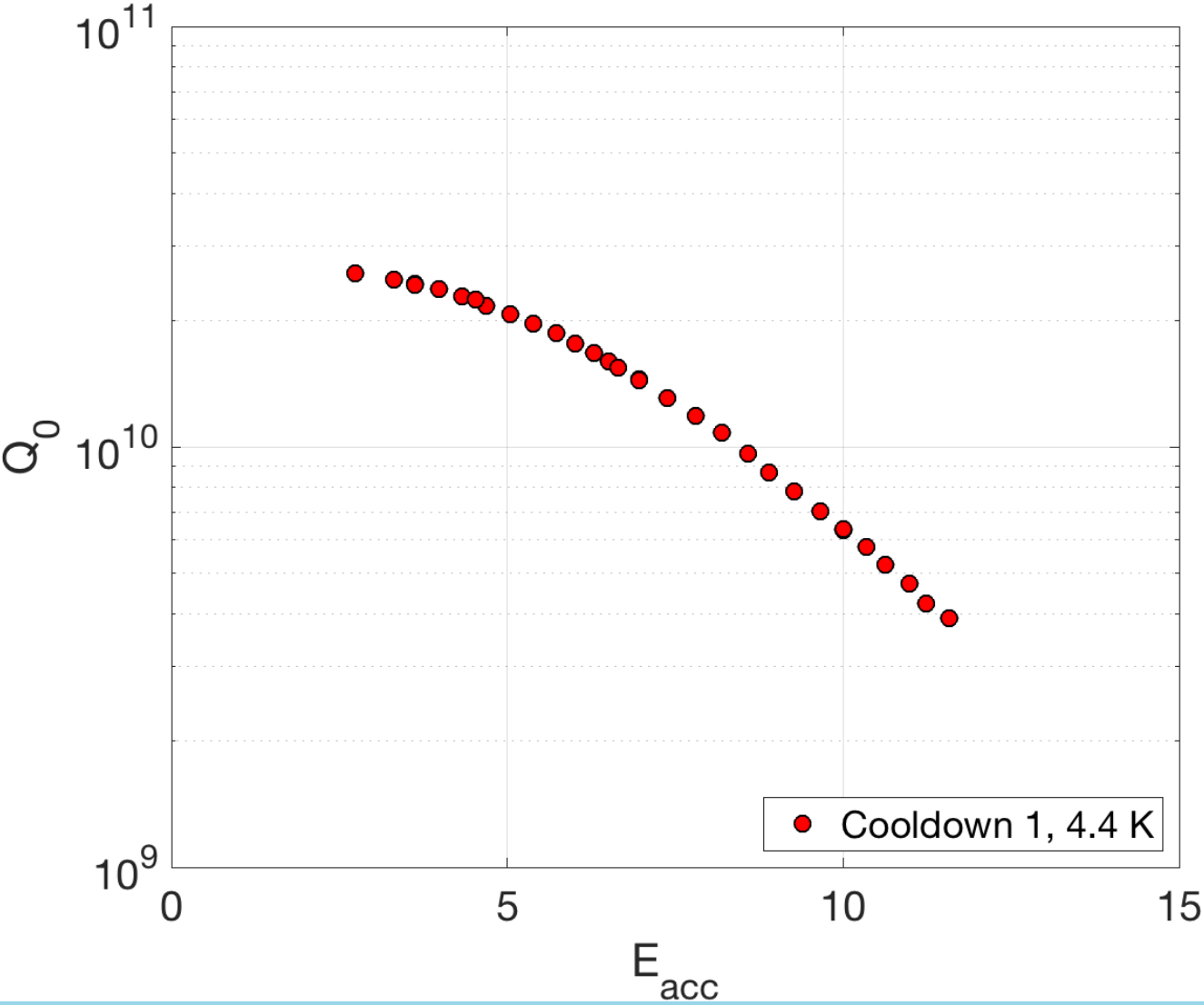
Q vs E at 4.4 K in liquid

The screenshot displays a control interface with several key sections:

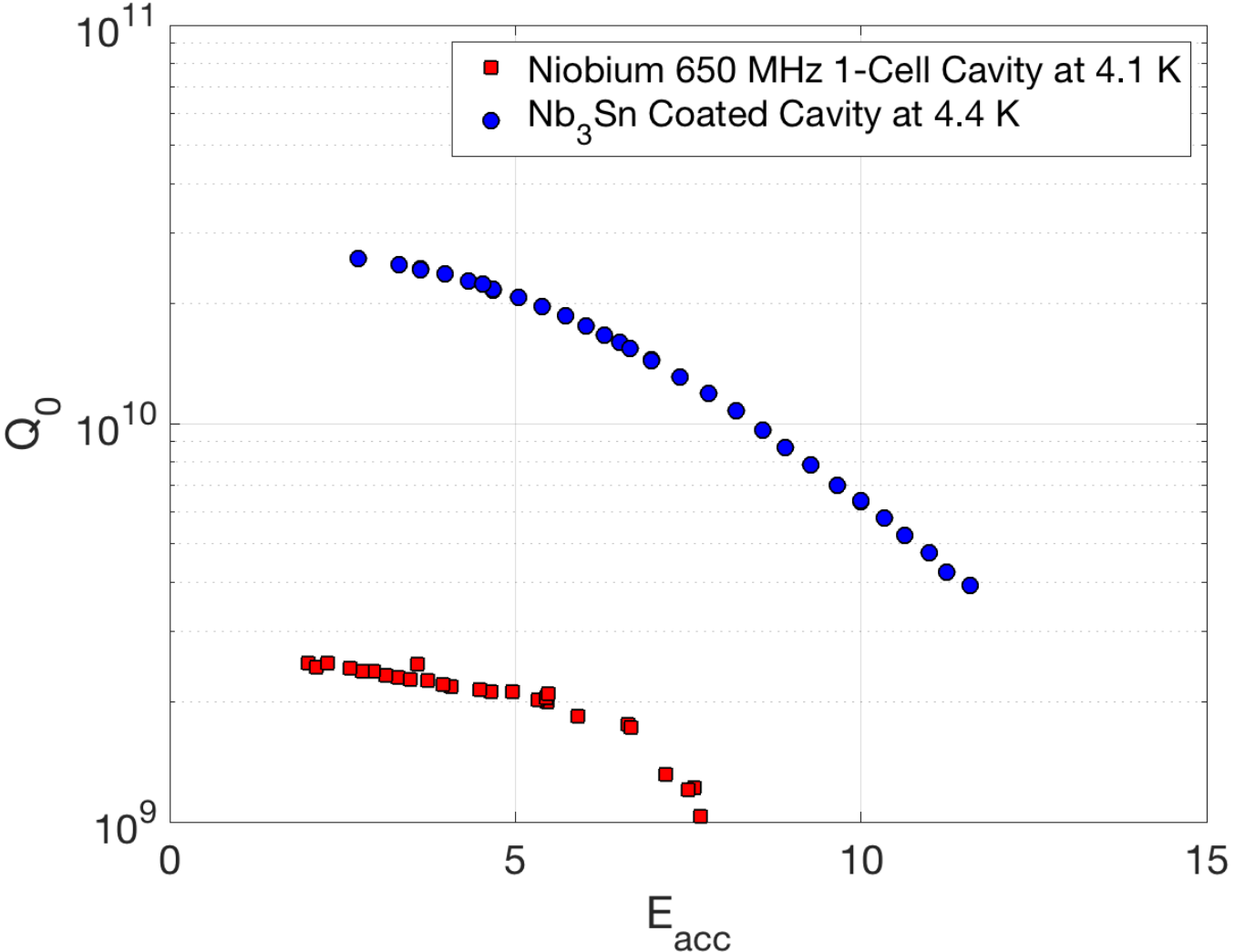
- 1-cell high:** Includes buttons for Backup Files, Zero Pwr Meters, Calibrate Cables, Change RF Source, and Clear Graph. It shows data file name B9AS-AES-002_2018-09-25_11-52.txt and temperature readings (Meas Temp, AUX Temp, Dewar Temp).
- CW measurements:** Lists parameters such as Pinc, Pref, Ptran, Ploss, P HOM A, P HOM B, Qo - CW, Eacc - CW, and Frequency.
- Pt Overload RF Control:** Features a vertical Atten (dB) scale, a Theta (deg) dial, and buttons for Set mixer level and Measure & Log CW.
- Radiation vs. Time:** A graph showing radiation levels over time, with a 'Mute Rad Alarm' button.
- Rad 1.34E-2 mR/hr:** Displays radiation rate and a 'STOP' button.
- Qo vs Eacc:** A large graph at the bottom showing the relationship between Qo and Eacc, with annotations for 'Initial cooldown - too fast' and 'Multipacting (limiting)'.



Cooldown 1 – 4.4 K Q vs E



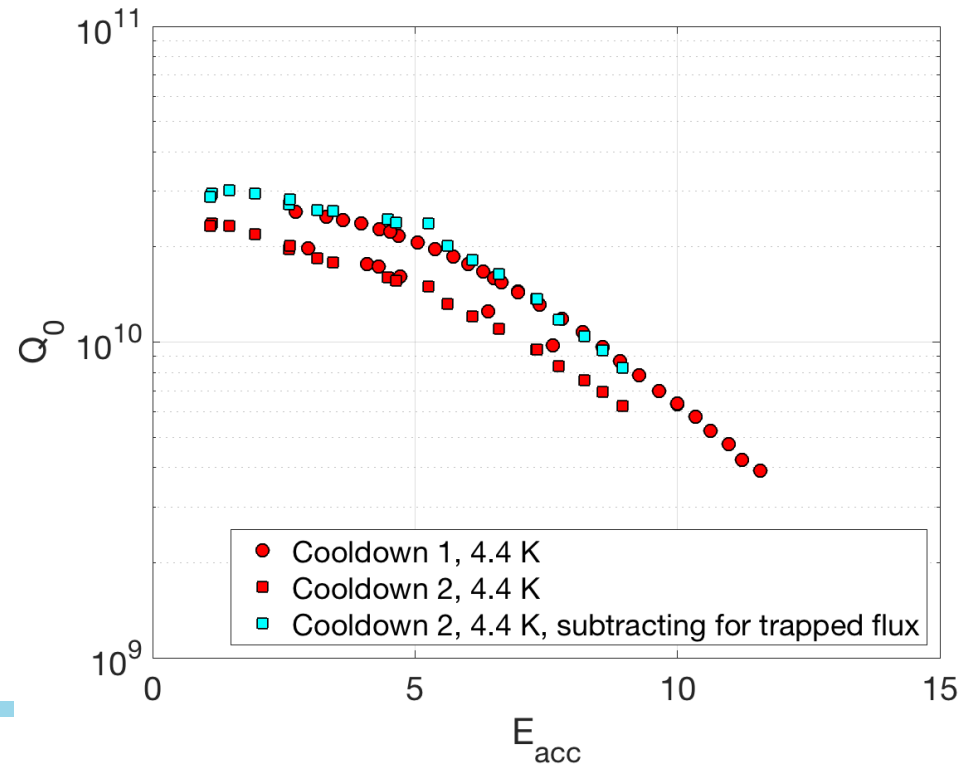
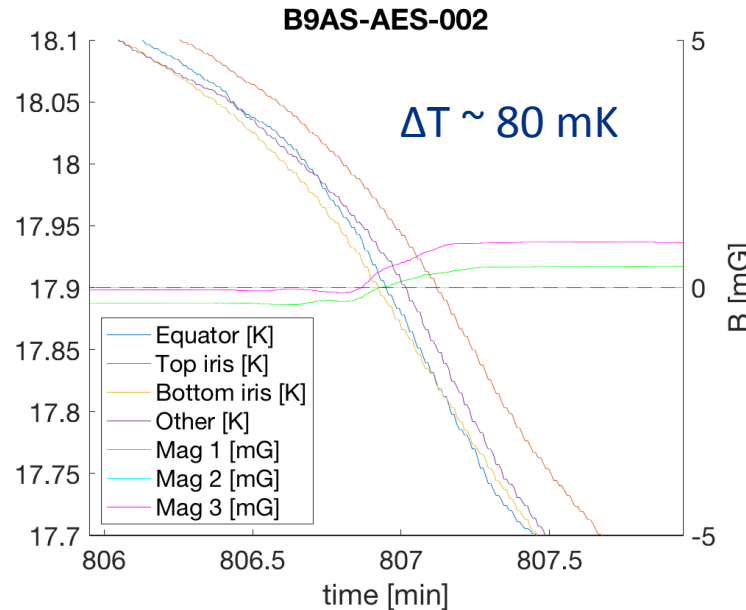
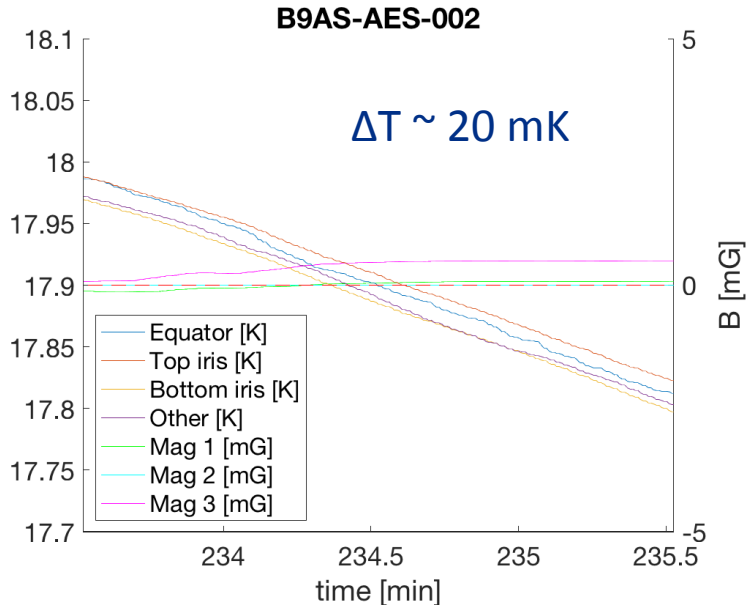
Q vs E Comparison to Before Coating



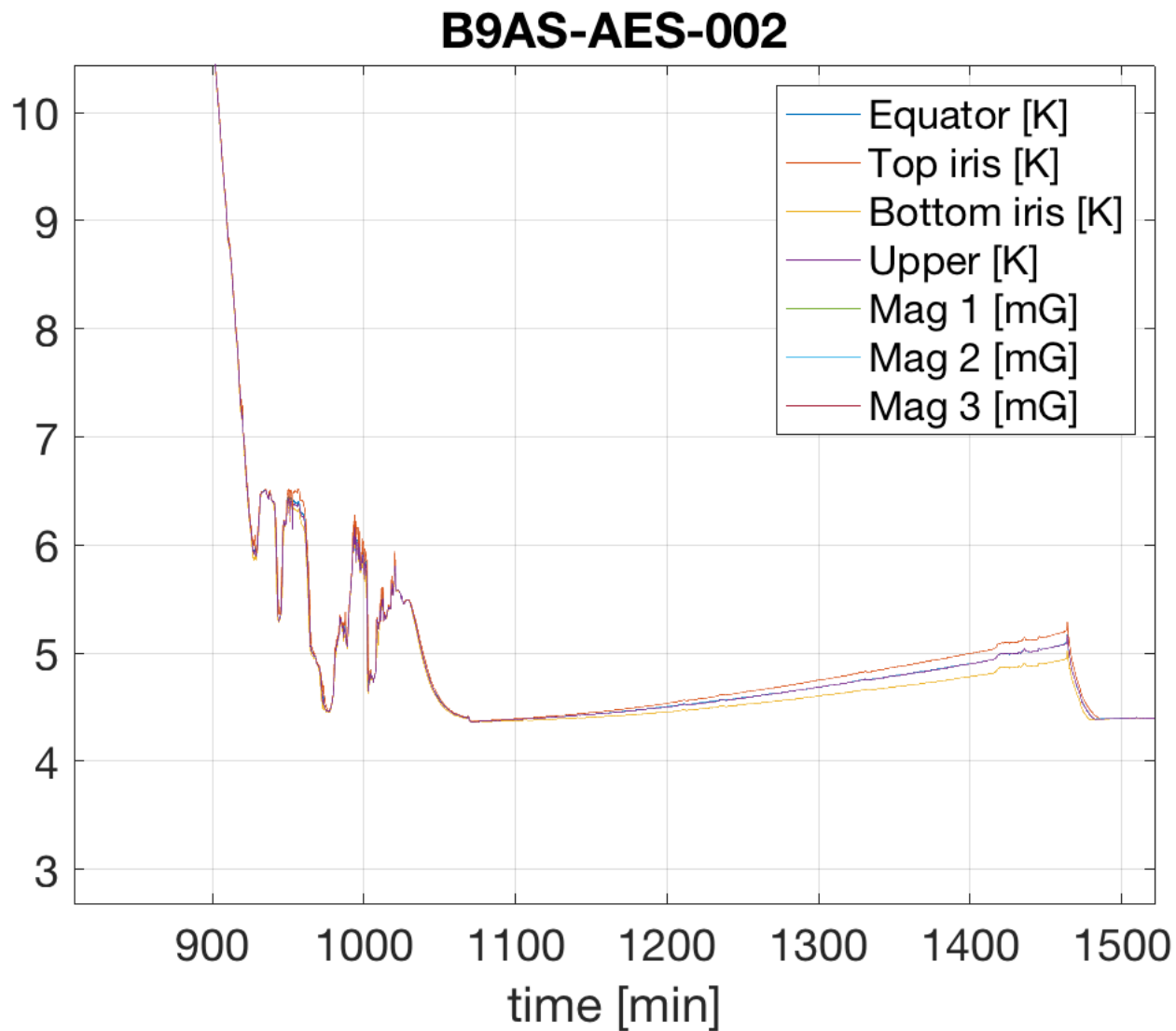
Day 2

Note on Cooldown

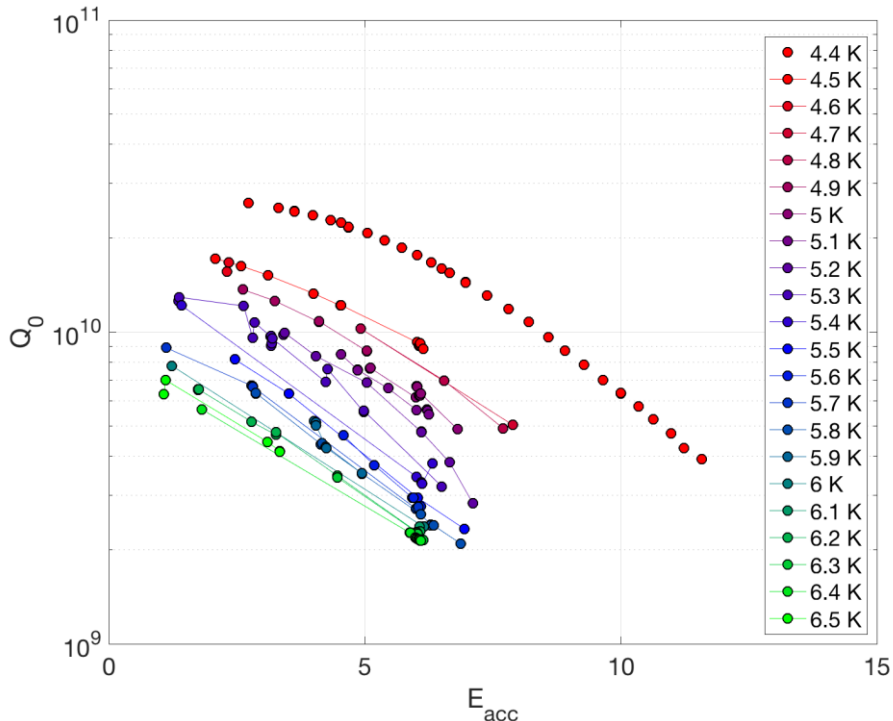
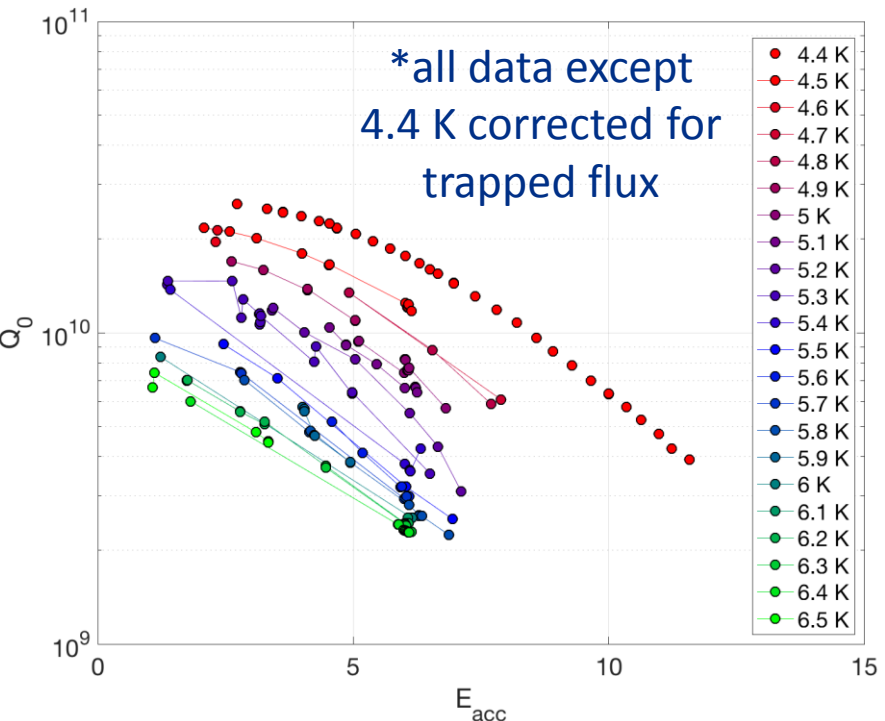
- Uniformity of cooldown is extremely important
- Full recalibration applied to double check data
- Correction applied to data from 2nd cooldown (incl. data in gas) to subtract effect of trapped flux



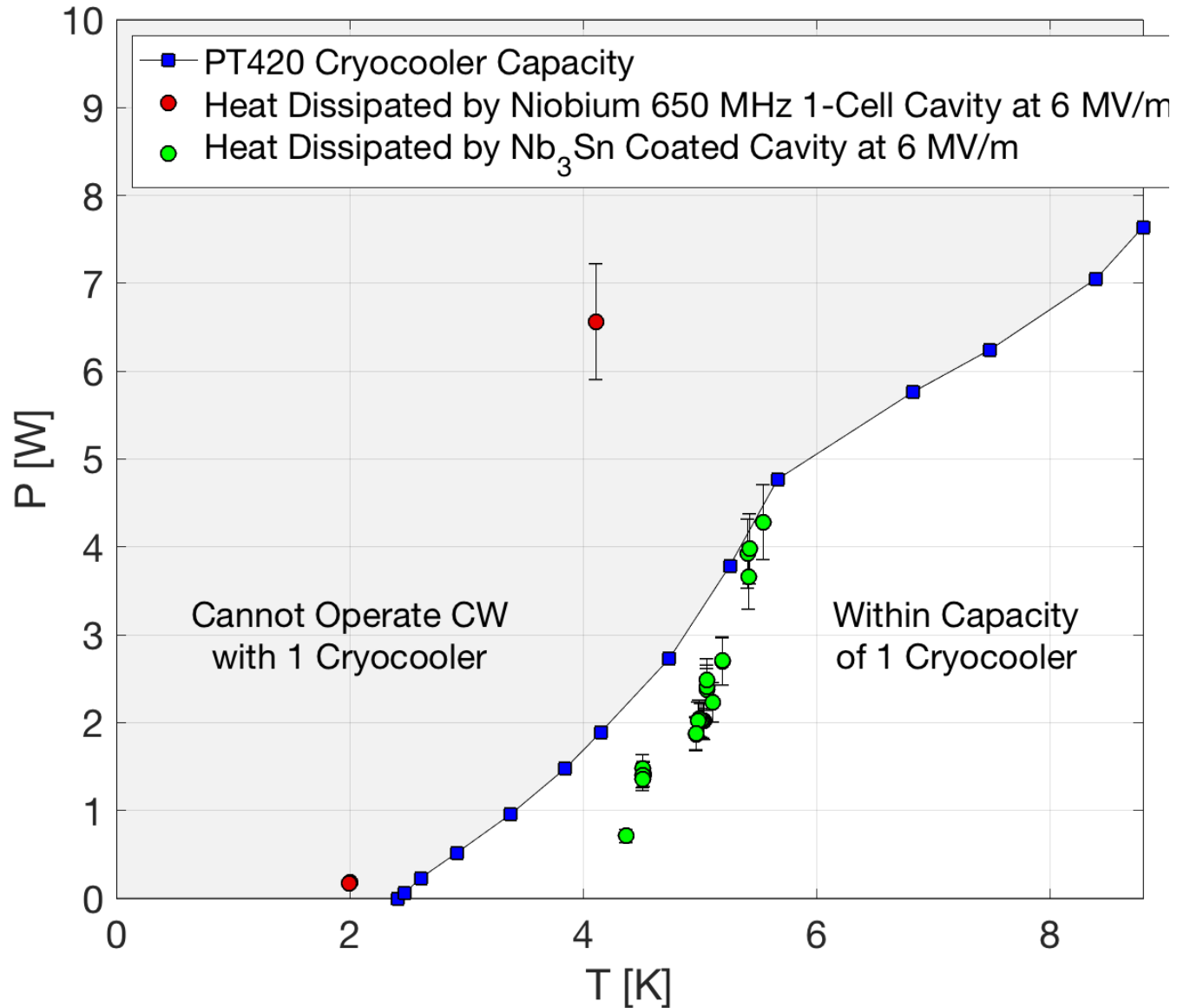
Measurements in Gas



Q vs E – including measurements in gas*

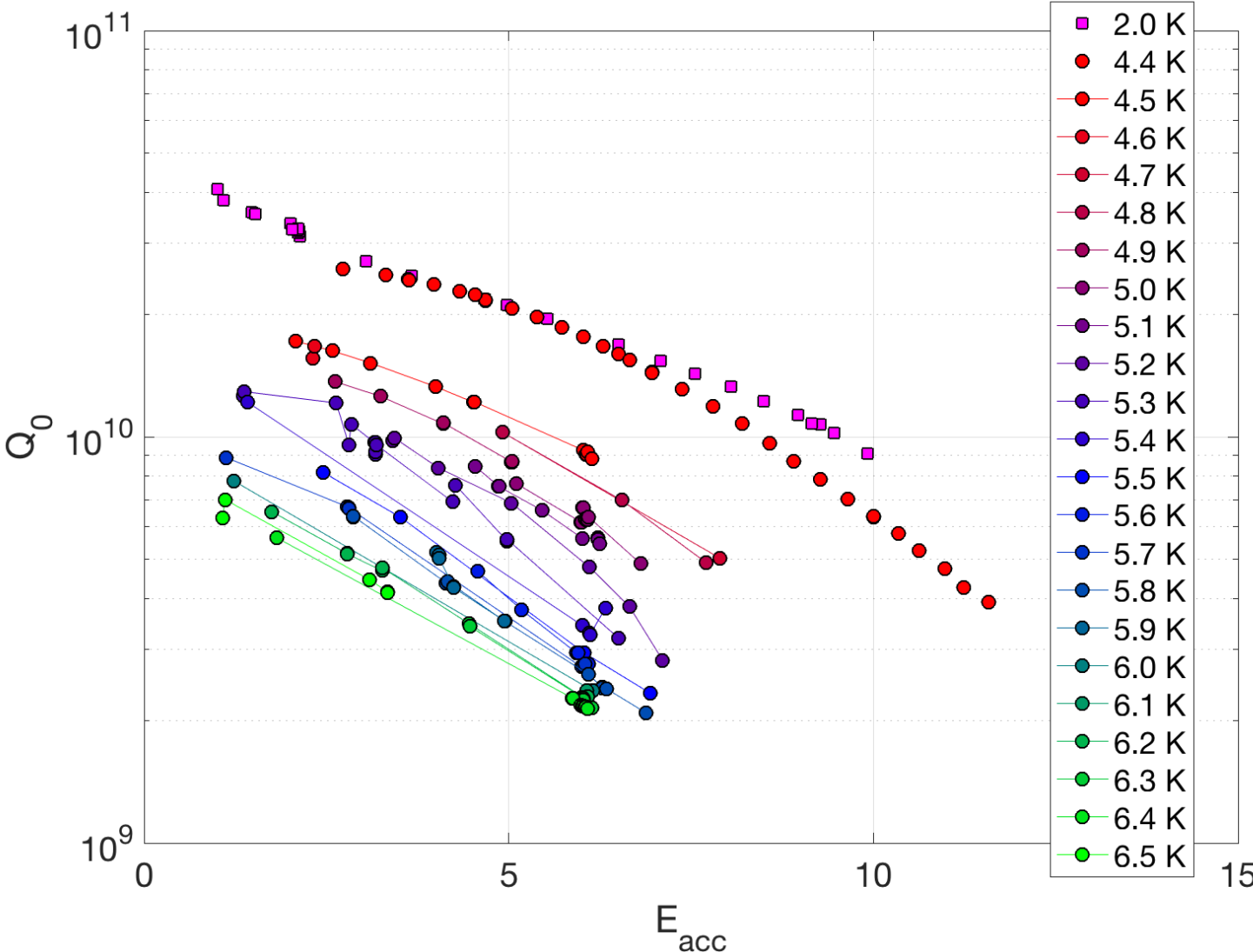


Dissipated Power Compared to Before Coating

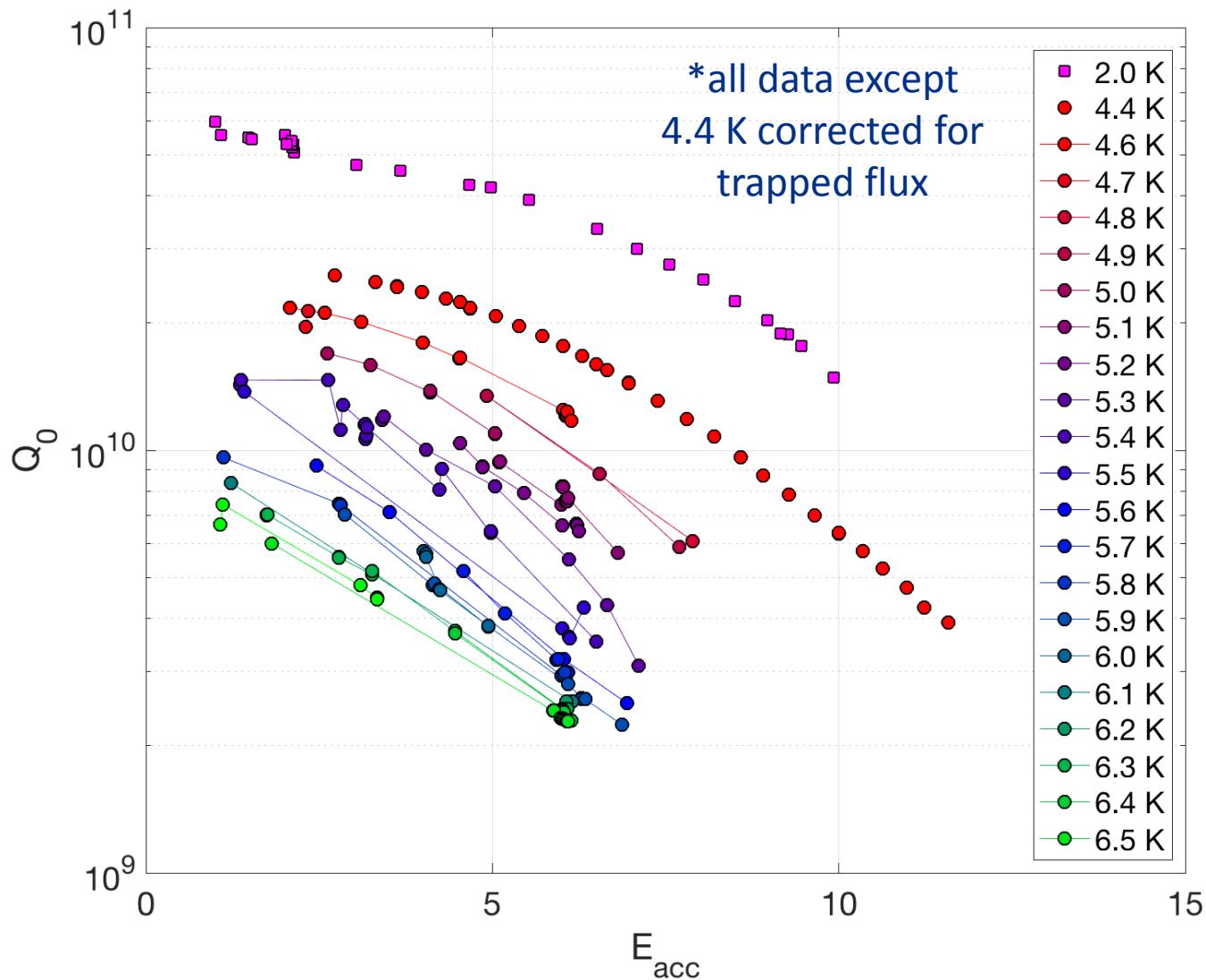


Day 3

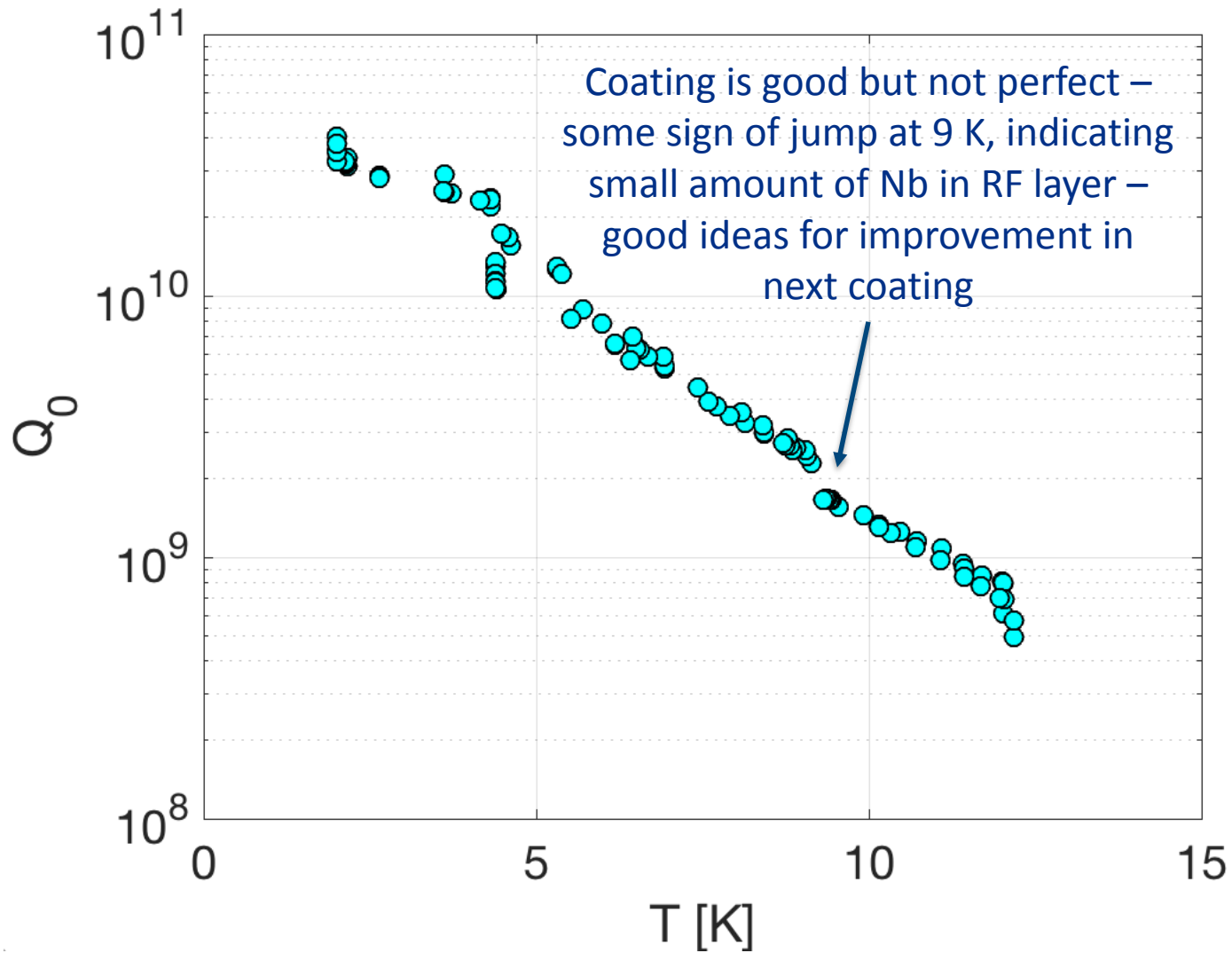
Measurement at 2.0 K – as measured



Measurement at 2.0 K – corrected for trapped flux



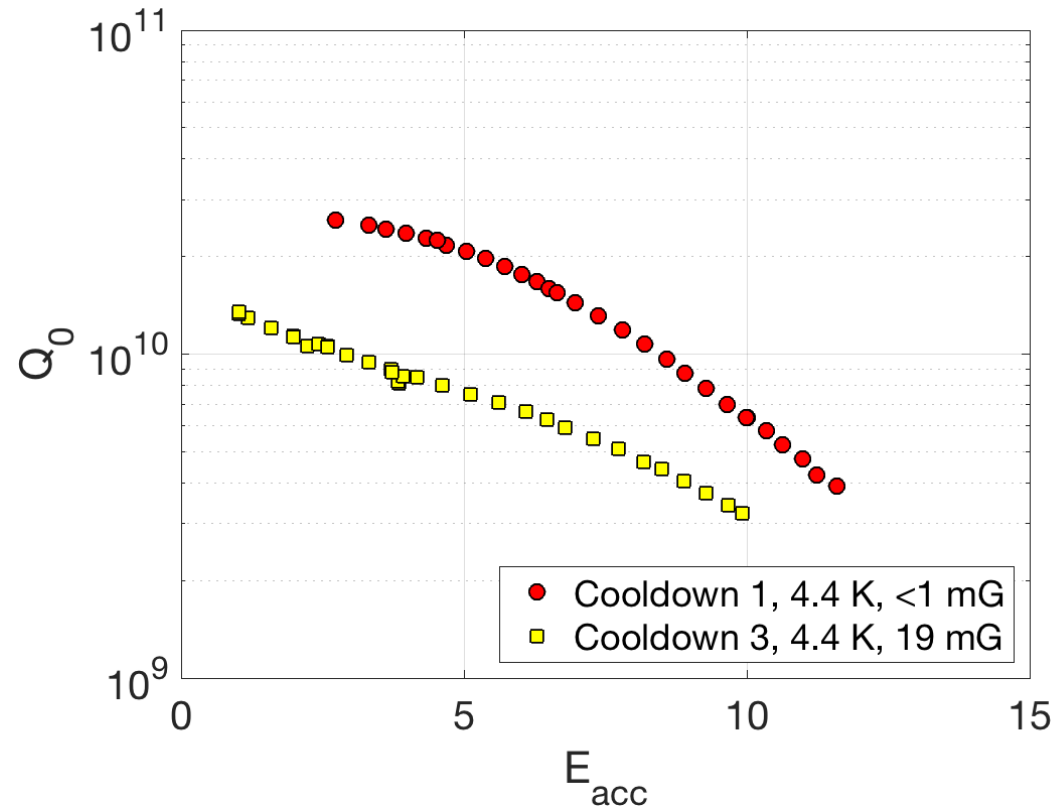
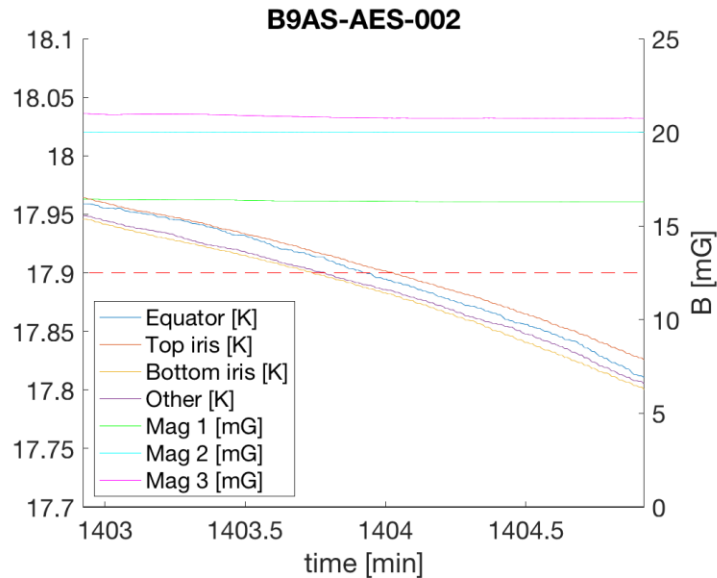
Low Field Q vs T



Day 4

Measurement after Trapping ~19 mG Field

- Added R_s at 5 MV/m: 21 n Ω – assuming linear, sensitivity ~1.1 n Ω /mG trapped
- Added R_s at 10 MV/m: 39 n Ω – assuming linear, sensitivity ~2.1 n Ω /mG trapped



Summary and Outlook

- **Nb₃Sn** offers a path to **operation at higher temperatures**, where cooling is substantially more efficient, potentially opening new applications
- **For high gradient applications**, experimentation and improving understanding of film growth processes brings us closer to realizing the full potential of this promising material
- **Nb₃Sn focus for near future:**
 - Reproducibility on single cells
 - Push to remove Q-slope and increase maximum gradient
 - Move into other frequencies and into multicells

